

DHG20C600PB

Sonic Fast Recovery Diode

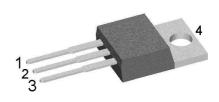
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V_{RRM}	=	600 V	
I _{fav}	<i>=</i> 2x	10 A	
t _{rr}	=	35 ns	

preliminary

High Performance Fast Recovery Diode Low Loss and Soft Recovery **Common Cathode**

Part number

DHG20C600PB



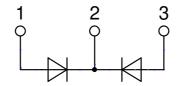
Package: TO-220

RoHS compliant

• Industry standard outline

• Epoxy meets UL 94V-0

Backside: cathode



Features / Advantages:

- Planar passivated chips
- · Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- · Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

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Fast Diode					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V	
V _{RRM}	max. repetitive reverse blocking vo	oltage	$T_{vJ} = 25^{\circ}C$			600	V	
I _R	reverse current, drain current	V_{R} = 600 V	$T_{VJ} = 25^{\circ}C$			30	μA	
		V_{R} = 600 V	$T_{vJ} = 125^{\circ}C$			1.2	mA	
V _F	forward voltage drop	I _F = 10 A	$T_{VJ} = 25^{\circ}C$			2.23	V	
		I _F = 20 A				3.13	V	
		$I_{F} = 10 \text{ A}$	T _{vJ} = 125°C			2.18	V	
		$I_{F} = 20 \text{ A}$				3.29	V	
I FAV	average forward current	$T_c = 95^{\circ}C$	T _{vJ} = 150°C			10	Α	
		rectangular d = 0.5						
V _{F0}	threshold voltage		T _{vJ} = 150°C			1.04	V	
r _F	slope resistance } for power lo	ss calculation only				104	mΩ	
\mathbf{R}_{thJC}	thermal resistance junction to case	2				1.8	K/W	
\mathbf{R}_{thCH}	thermal resistance case to heatsin	k			0.5		K/W	
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			70	W	
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			80	Α	
C	junction capacitance	$V_{R} = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		6		pF	
I _{RM}	max. reverse recovery current		$T_{vJ} = 25 °C$		4		Α	
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}$	T _{vJ} = °C		tbd		Α	
t _{rr}	reverse recovery time	I _F = 10 A; V _R = 400 V -di _F /dt = 200 A/μs	$T_{VJ} = 25 \degree C$		35		ns	
	J		T _{vJ} = °C		tbd		ns	

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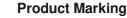
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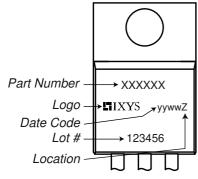


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Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
	RMS current	per terminal "			35	Α
T _{vj}	virtual junction temperature		-55		150	°C
T _{op}	operation temperature		-55		125	°C
T _{stg}	storage temperature		-55		150	°C
Weight				2		g
M _D	mounting torque		0.4		0.6	Nm
F _c	mounting force with clip		20		60	Ν





Part description

- D = Diode
- H = Sonic Fast Recovery Diode
- G = extreme fast 20 = Current Rating [A]
- C = Common Cathode
- 600 = Reverse Voltage [V] PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG20C600PB	DHG20C600PB	Tube	50	505287

Similar Part	Package	Voltage class
DHG20C600QB	TO-3P (3)	600

Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 150^{\circ}C$
	$-R_0$	Fast Diode		
V _{0 max}	threshold voltage	1.04		V
$\mathbf{R}_{0 \max}$	slope resistance *	101		mΩ

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